

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
I_K	Reverse Breakdown Current	20	mA
I_F	Forward Current	10	mA
P_D	Power Dissipation (note 1) SOT23-3	360	mW
T_{Std}	Storage Temperature	-65 to +150	°C
T_J	Junction Temperature	+150	°C
T_{Lead}	Lead Temperature (soldering, 10 seconds)	+260	°C
ESD	Human Body Model (HBM) (note 2)	2	kV
	Machine Model (MM) (note 2)	200	V

Note 1: The maximum power dissipation must be derated at high temperature. It can be calculated using T_{JMAX} (maximum junction temperature), R_{THJA} (Thermal resistance junction to ambient) and T_A (Ambient temperature). The maximum power dissipation formula at any temperature is $P_{DMAX} = (T_{JMAX} - T_A) / R_{THJA}$. R_{THJA} is 340°C/W for the SOT23-3 package.

Note 2: The Human Body Model (HBM) is defined as a 100pF capacitor discharge through a 1.5kΩ resistor into each pin.
The Machine Mode (MM) is defined as a 200pF capacitor discharge directly into each pins.

OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
I_{min}	Minimum Operating Current	40	μA
I_{max}	Maximum Operating Current	12	mA
T_{oper}	Operating Free Air Temperature Range	-40 to +85	°C

ELECTRICAL CHARACTERISTICS (note 3)

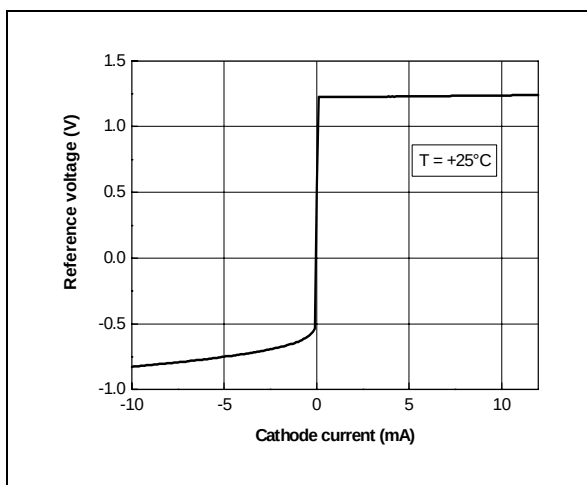
$T_{amb} = 25^\circ\text{C}$ (unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
V_K	Reverse Breakdown Voltage	$I_K = 100\mu\text{A}$	1.213	1.225	1.237	V
	Reverse Breakdown Voltage Tolerance	$I_K = 100\mu\text{A}$ $-40^\circ\text{C} < T_{amb} < +85^\circ\text{C}$	-12 -16		+12 +16	mV
I_{KMIN}	Minimum Operating Current	$T_{amb} = 25^\circ\text{C}$		40	45	μA
		$-40^\circ\text{C} < T_{amb} < +85^\circ\text{C}$			50	
$\Delta V_K / \Delta T$	Average Temperature Coefficient (note 4)	$I_K = 100\mu\text{A}$			50	ppm/°C
$\Delta V_K / \Delta I_K$	Reverse Breakdown Voltage Change with Operating Current Range	$I_{KMIN} < I_K < 1\text{mA}$ $-40^\circ\text{C} < T_{amb} < +85^\circ\text{C}$		0.3	1 1.5	mV
		$1\text{mA} < I_K < 12\text{mA}$ $-40^\circ\text{C} < T_{amb} < +85^\circ\text{C}$		2.5	8 10	
R_{KA}	Static Impedance	$\Delta I_K = I_{KMIN}$ to 1mA $-40^\circ\text{C} < T_{amb} < +85^\circ\text{C}$		0.3	1 1.5	Ω
		$\Delta I_K = 1\text{mA}$ to 12mA $-40^\circ\text{C} < T_{amb} < +85^\circ\text{C}$		0.25	0.7 0.9	
K_{VH}	Long Term Stability	$I_K = 100\mu\text{A}$, $t = 1000\text{hrs}$		120		ppm
E_N	Wide Band Noise	$I_K = 100\mu\text{A}$ $100\text{Hz} < f < 10\text{kHz}$		200		nV/√Hz

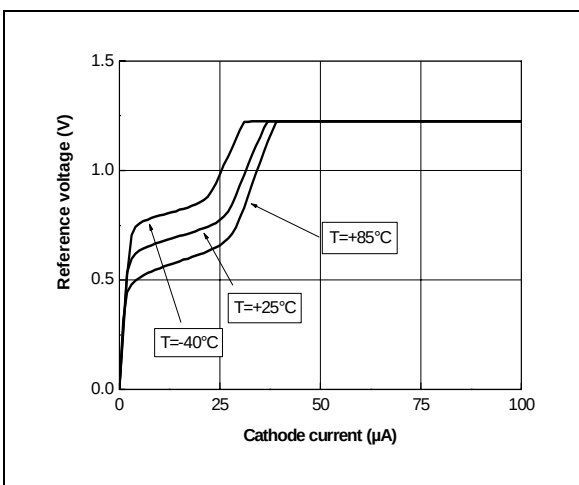
Note 3: Limits are 100% production tested at 25°C. Limits over temperature are guaranteed through correlation and by design.

Note 4: The total tolerance within the industrial range, where the maximum ΔT versus 25°C is 65°C, is explained hereafter:
 $\pm 1\% + (\pm 50 \text{ ppm}/^\circ\text{C} \times 65^\circ\text{C}) = \pm 1.325\%$

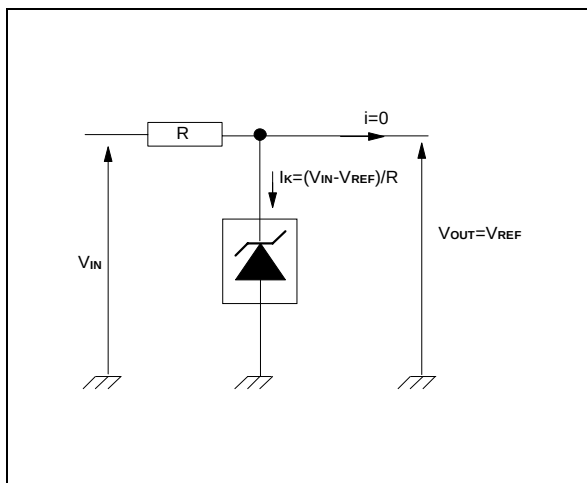
Reference voltage versus cathode current



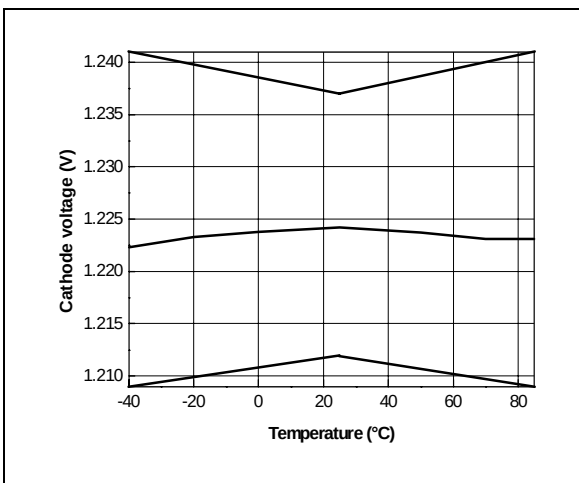
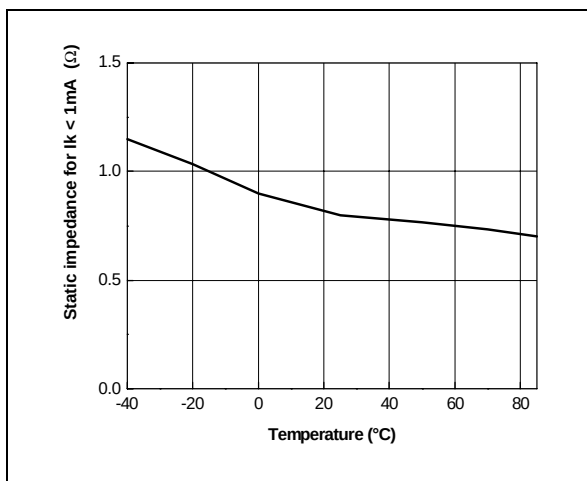
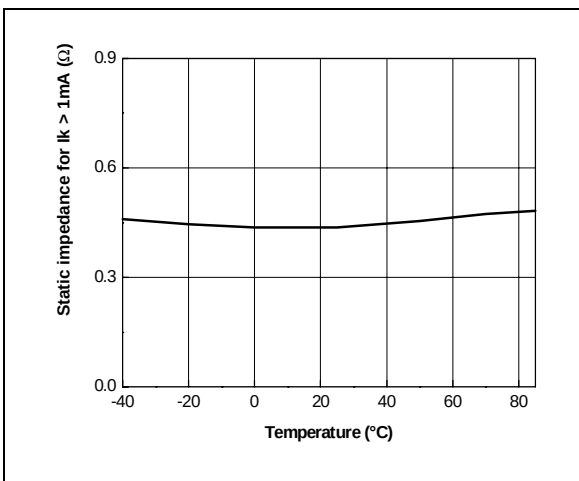
Reference voltage versus cathode current



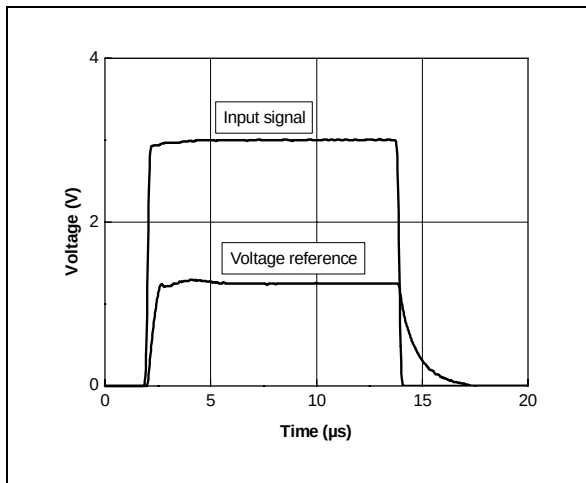
Test circuit



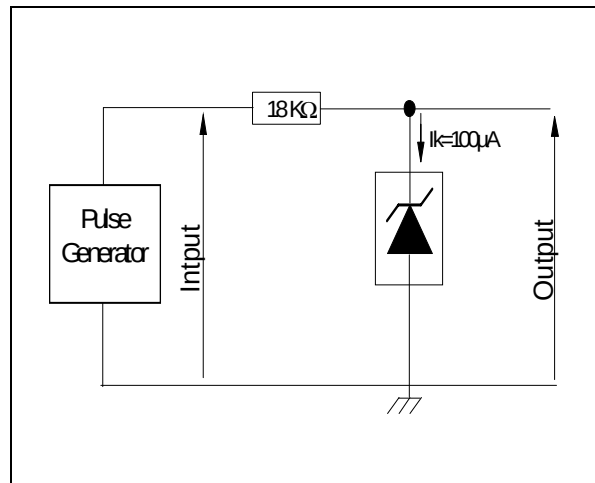
Reference voltage versus Temperature

Static impedance for $I_K < 1\text{mA}$ Static impedance for $I_K > 1\text{mA}$ 

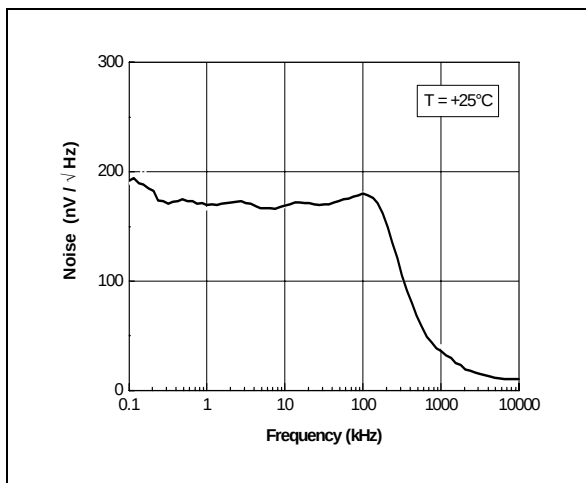
Start-Up characteristics with low I_k (100 μ A)

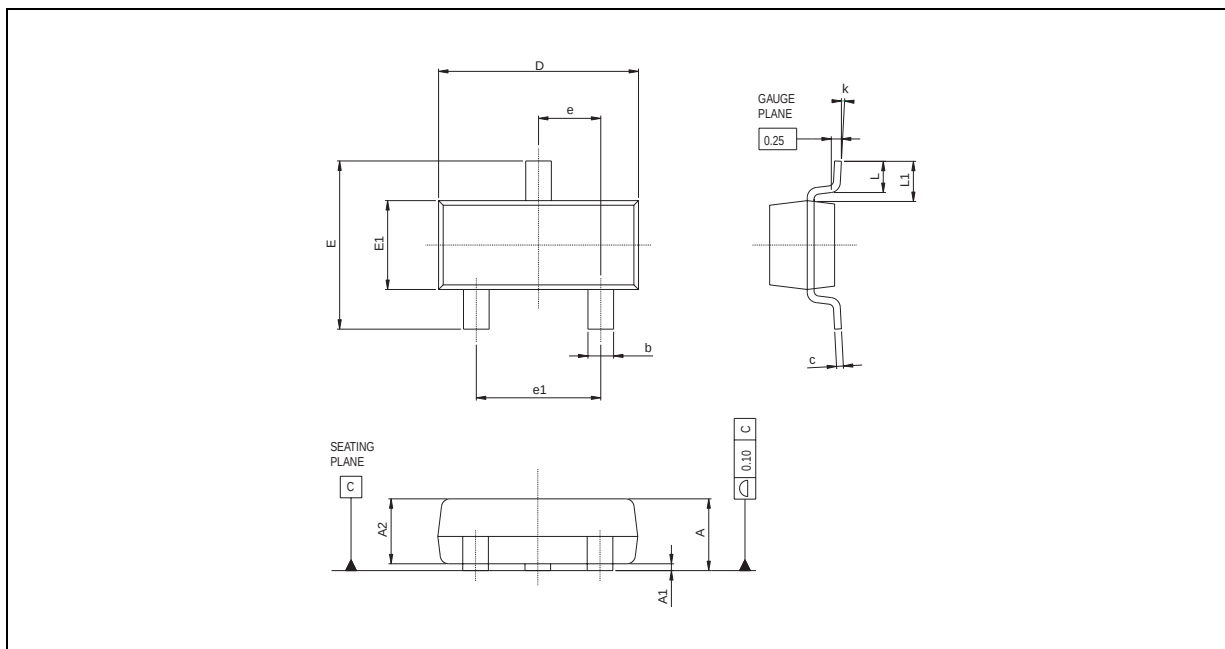


Start-Up schematic with low I_k (100 μ A)



Noise versus frequency



PACKAGE MECHANICAL DATA**3 PINS - TINY PACKAGE (SOT23-3)**

Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.890		1.120	0.035		0.044
A1	0.010		0.100	0.0004		0.004
A2	0.880	0.950	1.020		0.037	0.040
b	0.300		0.500	0.012		0.020
c	0.080		0.200	0.003		0.008
D	2.800	2.900	3.040	0.110	0.114	0.120
E	2.100		2.640	0.083		0.104
E1	1.200	1.300	1.400	0.047	0.051	0.055
e		0.950			0.037	
e1		1.900			0.075	
L	0.400	0.500	0.600	0.016	0.020	0.024
L1		0.540			0.021	
k	0°		8°			

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